

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|-------|--|---|------------------|---------|------------------|
| L1 | 28979 | SOI (silicon near on near insulator) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/09 11:00 |
| L2 | 94247 | MOSFET (Metal near oxide near semiconductor near field near effect near transistor) misfet | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/09 11:01 |
| L3 | 694 | channel with (fully near deplet\$3) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/09 11:01 |
| L4 | 350 | 1 and 2 and 3 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/11/09 11:01 |